

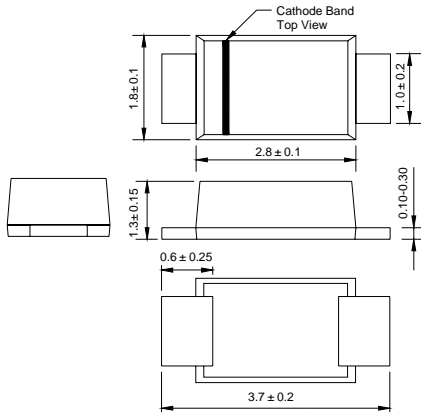


# SOD4001 THRU SOD4007

## SURFACE MOUNT GENERAL PURPOSE SILICON RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

### SOD-123FL



### FEATURES

- ◆ Glass passivated device
- ◆ Ideal for surface mounted applications
- ◆ Low reverse leakage
- ◆ Metallurgically bonded construction
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length,  
5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC SOD-123FL molded plastic body over passivated chip  
**Terminals:** Solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.0007 ounce, 0.02 grams

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

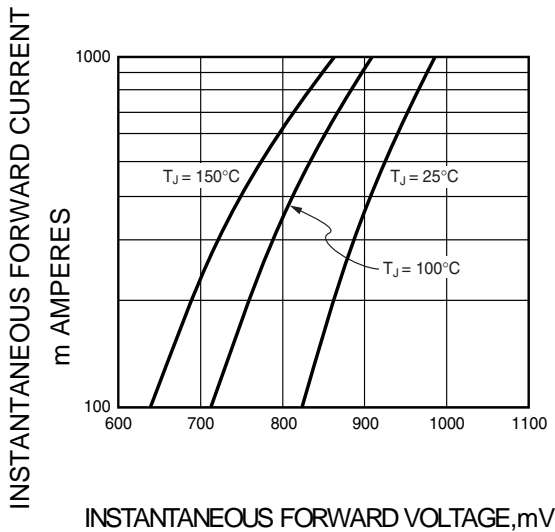
Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	4001	4002	4003	4004	4005	4006	4007	UNITS
MDD Catalog Number		D1	D2	D3	D4	D5	D6	D7	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_A=65^\circ\text{C}$ (NOTE 1)	$I_{(AV)}$	1.0							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) $T_L=25^\circ\text{C}$	$I_{FSM}$	25.0							Amps
Maximum instantaneous forward voltage at 1.0A	$V_F$	1.1							Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	$I_R$	10.0 50.0							$\mu\text{A}$
Typical junction capacitance (NOTE 2)	$C_J$	4							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	180							K/W
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150							$^\circ\text{C}$

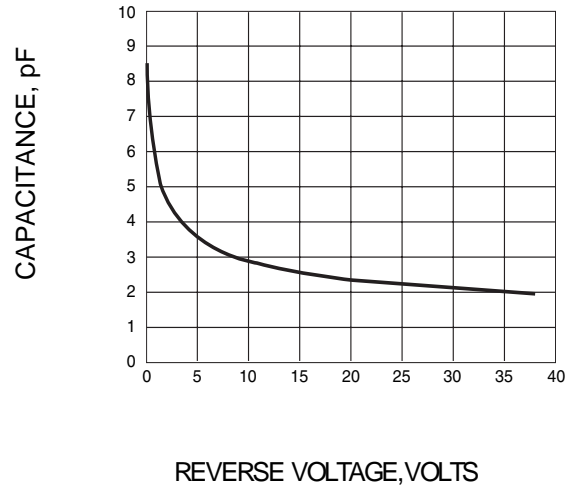
- Note:**
1. Averaged over any 20ms period.
  2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
  3. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

# RATINGS AND CHARACTERISTIC CURVES SOD4001 THRU SOD4007

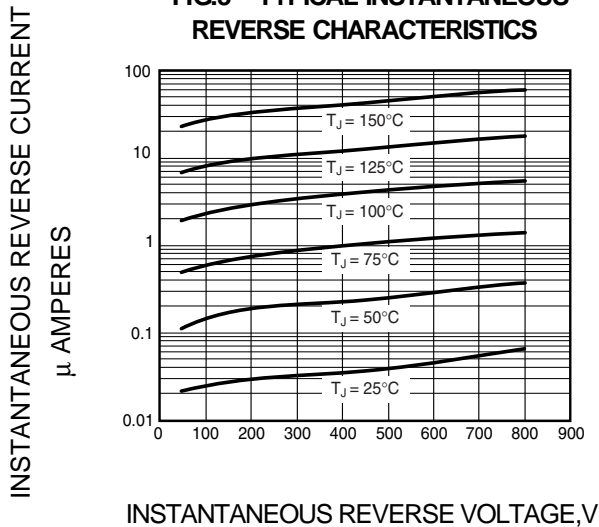
**FIG.1 – TYPICAL FORWARD CHARACTERISTIC**



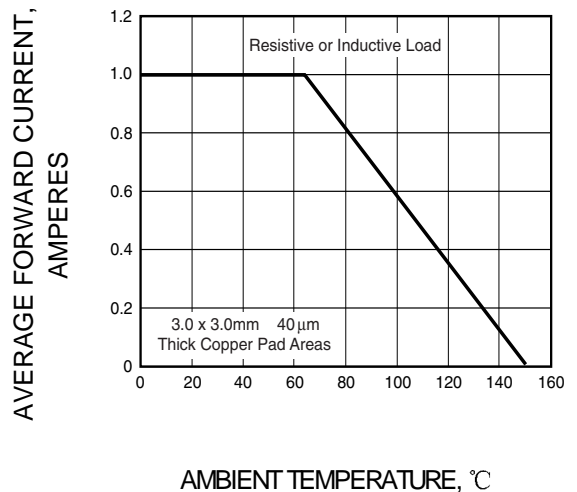
**FIG.2 – TYPICAL JUNCTION CAPACITANCE**



**FIG.3 – TYPICAL INSTANTANEOUS REVERSE CHARACTERISTICS**



**FIG.4 – FORWARD DERATING CURVE**



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